- Single-Chip Interface Solution for AppleTalk[™] and LocalTalk[™]
- Designed to Operate Up To 1 Mbps In AppleTalk and LocalTalk
- Switched-Capacitor Voltage Converter Allows for Single 5-V Operation
- 4-kV ESD Protection on Bus Terminals
- Combines Multiple Components into a Single Chip Solution
- LinBiCMOS[™] Process Technology

description

The SN75LBC775 is a low-power LinBiCMOS[™] device that incorporates the drivers and receivers for an AppleTalk or a LocalTalk interface and a switched-capacitor voltage converter for a single 5-V supply operation. LocalTalk uses a hybrid of RS-422 with the transceiver connected to the network through a small isolation transformer. The AppleTalk mode provides point-to-point communications and uses the same differential driver and receiver as LocalTalk with the addition of a hybrid RS-423, single-ended handshake driver (HSK) and receiver. In the AppleTalk mode, the port connects directly to the receiver with no isolation transformer.

While the device power is turned off ($V_{CC} = 0$) or disabled in the LocalTalk mode, the outputs are in a high-impedance state. When the driver enable (DEN) terminal is high, both the differential and serial driver outputs are in a high-impedance state.

The receiver output can be disabled and becomes a high impedance when the REN terminal is low.

A switched-capacitor voltage converter generates the negative voltage required from a single 5-V supply using two 22- μ F capacitors. One capacitor is between the C+ and C- terminals and the second is between V_{SS} and ground.

The SN75LBC775 is characterized for operating over the temperature range of 0°C to 70°C.



functional diagram





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SN75LBC775 SINGLE-CHIP APPLETALKTM AND LOCALTALKTM TRANSCEIVER

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INPUT		ENABLE	OUTPUT		
DA	HSKA	DEN	Α	В	HSKY
Н	Х	L	Н	L	Х
L	Х	L	L	Н	Х
Х	н	L	Х	Х	L
Х	L	L	Х	Х	н
OPEN	OPEN	L	н	L	L
х	х	н	z	Z	Z
Х	х	OPEN	Z	Z	Z
H = high level, L = low level, X = irrelevant,					

DRIVER FUNCTION TABLE

RECEIVER FUNCTION TABLE

INPUT	ENABLE	OUTPUT
RA RB	REN	RY
H L	Н	Н
LH	н	L
OPEN	н	Н
SHORT [†]	н	?
х	L	Z

 $1 - 0.2 V < V_{ID} < 0.2 V$

Z = high impedance (off) ? = indeterminate,

schematics of inputs and outputs





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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage range V/oo (see Note 1)	-0.5 to 7 V
	7 to 0 5 10 7 V
Supply voltage range, v _{SS}	-7 to 0.5 V
Receiver input voltage range, V _I (RA)	–15 V to 15 V
Receiver differential input voltage range, V _{ID}	12 V to 12 V
Receiver output voltage range, V _O (RY)	0.5 V to 5.5 V
Driver output voltage range, VO (Power Off) (DY, DZ, HSKY)	–15 V to 15 V
(Power On) (DY, DZ, HSKY)	11 V to 11 V
Driver input voltage range, VI (DA, HSKA, DEN, REN)	$\dots -0.5 \text{ V to V}_{CC} + 0.4 \text{ V}$
Electrostatic discharge (see Note 2) Class 3, A: Bus terminals	4 kV
All other terminals	2 kV
Continuous total power dissipation	See Dissipation Rating Table
Operating free-air temperature range, T _A	0°C to 70°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. All voltage values are with respect to network ground terminal unless otherwise noted.

2. This maximum rating is tested according to MIL-STD-883C, Method 3015.7.

DISSIPATION RATING TABLE

PACKAGE	T _A ≤ 25°C	DERATING FACTOR	T _A = 85°C
	POWER RATING	ABOVE T _A = 25°C	POWER RATING
DW	1125 mW	9.0 mW/°C	585 mW

recommended operating conditions

		MIN	NOM	MAX	UNIT
Supply voltage, V _{CC}			5	5.25	V
High-level input voltage, VIH	DA, HSKA, DEN, REN	2			V
Low-level input voltage, VIL	DA, HSKA, DEN, REN			0.8	V
Receiver input common-mode voltage range, V _{ICR} ‡		-7		7	V
Differential input voltage, V _{ID} \ddagger		-12		12	V
Voltage-converter filter capacitance					μF
Voltage-converter filter-capacitor equivalent series resistance (ESR)				2	Ω
Operating free-air temperature, TA		0		70	°C

[‡]The algebraic convention, in which the less-positive (more negative) limit is designated minimum, is used in this data sheet.



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DRIVER

electrical characteristics over recommend operating characteristics (unless otherwise noted)

	PARAMETE	R	TEST CO	NDITIONS	MIN	түр†	MAX	UNIT
VOH	High-level output voltage	Single ended	$P_{\rm b} = 2 k \Omega$	Soo Figuro 1	3.7			V
V _{OL}	Low-level output voltage	Single ended	KL = 3 KS2,	See Figure 1			-3.7	V
V _{OD}	Magnitude of differential out	put voltage (V _{DY} – V _{DZ})	See Figure 2		4.0	5.6		V
$\Delta V_{OD} $	Change in differential voltag	e magnitude	See Figure 2			10	250	mV
Voc	Common-mode output volta	ge‡	See Figure 3		-1		3	V
∆VOC(SS)	Change in steady-state com	mon-mode output voltage	See Figure 3				±200	mV
IOZ	High-impedance output current		V _{CC} = 0, -10 V	$' \le V_{O} \le 10 V$			±100	μΑ
IOS	Short-circuit output current		$-5 V \le V_0 \le 5 V_0$	/			450	mA
ICC	Supply current		DEN at 0 V, No load	REN at 5 V,		5	10	mA
IIН	High-level input current		V _I = 5 V				200	μΑ
1	All terminals except REN		N/- 0			-100	-200	μA
ЧL	REN	REN	v] = 0			-300	-455	μA

[†] All typical values are at V_{CC} = 5 V and T_A = 25°C.

[‡]The algebraic convention, in which the less positive (more negative) limit is designated minimum, is used in this data sheet.

switching characteristics over recommend operating conditions (unless otherwise noted)

PARAMETER			TEST CONDITIONS	MIN	TYP	MAX	UNIT
	Dranagation dalay time, high, to law layer	Single ended	-		155	300	ns
PHL	Propagation delay time, high- to low-level	Differential			115	180	ns
	Descention delegation laws to bigh lowed	Single ended			140	300	ns
PLH	Propagation delay time, low- to high-level	Differential			115	180	ns
t _{PZL}	 Propagation delay time, high-impedance to low-level output Propagation delay time, high-impedance to high-level output 				100	250	ns
^t PZH					100	250	ns
tPLZ	Z Propagation delay time, low-level to high-impedance output		Soo Eiguros 1 and 2		100	250	ns
tPHZ	Propagation delay time, high-level to high-impe	edance output			100	250	ns
	Piece time	Single ended			135	300	ns
۲	Rise unie	Differential			90	180	ns
		Single ended			145	300	ns
uf	Fall ume	Differential	1		95	180	ns
+	Pulso skow Ital tal	Single ended			15	50	ns
^t sk(p)	Pulse skew, IIPLH-IPHLI	Differential	1 1		2	22	ns



SN75LBC775 SINGLE-CHIP APPLETALKTM AND LOCALTALKTM TRANSCEIVER

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RECEIVER

electrical characteristics over recommended operating conditions (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	түр†	MAX	UNIT
VIT+	Positive-going differential input voltage threshold				200	mV
V _{IT} -	Negative-going differential input voltage threshold [‡]]	-200			mV
V _{hys}	Input voltage hysteresis (V _{IT+} - V _{IT-)}	$I_{OH} = 2 \text{ mA}, \qquad I_{OL} = -2\text{mA},$ See Figure 4		30		mV
VOH	High-level output voltage		2	4.5		V
VOL	Low-level output voltage				0.8	V
		$V_{O} = 0$	8	50	85	mA
OS	Snort-circuit output current+	VO = VCC	-85	-50	-8	mA
ri	Input resistance	$V_{CC} = 0 \text{ or } 5.25 \text{ V}, -12 \text{ V} \le \text{V}_I \le 12 \text{ V}$	6			kΩ

[†] All typical values are at V_{CC} = 5 V and T_A = 25°C.
 [‡] The algebraic convention, in which the less positive (more negative) limit is designated minimum, is used in this data sheet.

switching characteristics over recommended operating conditions (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP†	MAX	UNIT
t _{PHL}	Propagation delay time, high- to low-level output	R _L = 2 kΩ, C _L = See Figure 4	0. 45 -5		25	60	ns
^t PLH	Propagation delay time, low- to high-level output				22	60	ns
tr	Rise time		CL = 15 pF,		8	25	ns
t _f	Fall time				7	25	ns
^t SK(P)	Pulse skew, tpLH - tpHL				3	20	ns
t _{PZL}	Receiver output enable time to low-level output				50		ns
^t PZH	Receiver output enable time to high-level output		Soo Eiguro 5		50		ns
t _{PLZ}	Receiver output disable time to low-level output	$C_L = \delta U PF,$ See Fig	See Figure 5		50		ns
^t PHZ	Receiver output disable time to high-level output				50		ns

[†] All typical values are at $V_{CC} = 5$ V and $T_A = 25^{\circ}C$.



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PARAMETER MEASUREMENT INFORMATION









NOTE A: The input waveform t_f , $t_f < = 10$ ns





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PARAMETER MEASUREMENT INFORMATION















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TYPICAL CHARACTERISTICS

Figure 6



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APPLICATION INFORMATION

Figure 7. Receiving RS-423 Signals With a Differential Receiver



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MECHANICAL INFORMATION

DW (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

16 PIN SHOWN



NOTES: B. All linear dimensions are in inches (millimeters).

C. This drawing is subject to change without notice.

D. Body dimensions do not include mold flash or protrusion, not to exceed 0.006 (0,15).

E. Falls within JEDEC MS-013



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